

	Type	Hits	Search Text	DBs
1	IS&R	2	("6741623").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
2	IS&R	2	("5981977").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
3	IS&R	2	("5923690").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
4	BRS	8	laser and semiconductor and bur\$4 near layer with (algan or aluminum adj gallium adj nitride) and strip\$4 near shape and active near layer and group adj iii	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
5	BRS	46	laser and semiconductor and bur\$4 near layer and strip\$4 near shape and active near layer and group adj iii	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
6	BRS	8	laser and semiconductor and bur\$4 near layer with (algan or aluminum near gallium near nitride) and strip\$4 near shape and active near layer and group adj iii	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
7	BRS	8	laser and semiconductor and bur\$4 near layer with (algan or aluminum near2 gallium near2 nitride) and strip\$4 near shape and active near layer and group adj iii	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Time Stamp	Comments	Error or Definition	Errors	Ref #
1	2005/03/02 11:16				S1
2	2005/02/04 23:34				S2
3	2005/02/04 23:35				S3
4	2005/02/05 00:10				S5
5	2005/03/01 18:18				S4
6	2005/02/05 00:11				S6
7	2005/02/05 00:11				S7

	Type	Hits	Search Text	DBs
8	BRS	8	laser and semiconductor and bur\$4 near layer with (algan or aluminum near2 gallium near2 nitride or gaaln) and strip\$4 near shape and active near layer and group adj iii	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
9	BRS	12	laser and semiconductor and bur\$4 near layer with (algan or aluminum near2 gallium near2 nitride or gaaln) and strip\$4 near shape and active near layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
10	BRS	2	"2000150512"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
11	BRS	18	laser and semiconductor and bur\$4 near layer and strip\$4 near shape and active near layer and group adj iii and nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
12	BRS	62	(438/44).ccls. and nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
13	BRS	25	(438/44).ccls. and nitride and bur\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
14	BRS	18	(438/44).ccls. and nitride and bur\$4 and active near layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
15	BRS	23	(438/44).ccls. and (gallium or aluminum or indium) with nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
16	BRS	559	(372/45).ccls. and nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Time Stamp	Comments	Error or Definition	Errors	Ref #
8	2005/02/05 00:12				S8
9	2005/02/05 00:18				S9
10	2005/02/05 00:18				S10
11	2005/03/01 18:19				S11
12	2005/03/02 11:26				S13
13	2005/03/02 11:19				S14
14	2005/03/02 11:19				S15
15	2005/03/02 11:36				S16
16	2005/03/02 11:37				S18

	Type	Hits	Search Text	DBs
17	BRS	225	(372/45).ccls. and (aluminum or gallium or indium) with nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
18	BRS	180	(372/45).ccls. and (aluminum or gallium or indium) with nitride and active adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
19	BRS	82	(372/45).ccls. and (aluminum or gallium or indium) with nitride with active adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
20	BRS	51	(372/46).ccls. and (aluminum or gallium or indium) with nitride with active adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
21	BRS	51	(372/46).ccls. and (aluminum or gallium or indium) with nitride with active adj layer and (laser or emit\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Time Stamp	Comments	Error or Definition	Errors	Ref #
17	2005/03/02 11:38				S19
18	2005/03/02 11:38				S20
19	2005/03/02 11:43				S21
20	2005/03/02 11:43				S22
21	2005/03/02 11:44				S23